

PMEG4020ETP

40 V, 2 A low VF MEGA Schottky barrier rectifier Rev. 1 — 5 October 2011 Pro

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD128 small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Average forward current: I_{F(AV)} ≤ 2 A
- Reverse voltage: V_R ≤ 40 V
- Low forward voltage
- High power capability due to clip-bonding technology

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply

1.4 Quick reference data

- Small and flat lead SMD plastic package
- AEC-Q101 qualified
- High temperature T_i ≤ 175 °C
- Reverse polarity protection
- Low power consumption applications
- High temperature applications

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{amb} ≤ 110 °C	<u>[1]</u>	-	-	2	А
		square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 165 °C		-	-	2	А
V _R	reverse voltage	T _j = 25 °C		-	-	40	V
V _F	forward voltage	I _F = 2 A; T _j = 25 °C		-	430	490	mV
I _R	reverse current	$T_j = 25 \text{ °C}; V_R = 40 \text{ V}$		-	25	100	μA

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.



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2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode ^[1]		. 54 -
2	А	anode	1	1 🕂 2
				sym001
			SOD128	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering in	nformation		
Type number	Package		
	Name	Description	Version
PMEG4020ETP	-	plastic surface-mounted package; 2 leads	SOD128

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMEG4020ETP	C2

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage	T _j = 25 °C		-	40	V
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{amb} ≤ 110 °C	<u>[1]</u>	-	2	A
		square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 165 °C		-	2	A
I _{FSM}	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$		-	50	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2][3]	-	750	mW
			[4][3]	-	1250	mW
			[1][3]	-	2500	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Reflow soldering is the only recommended soldering method.

[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1][2][3]	-	-	200	K/W
	from junction to ambient		[1][4][3]	-	-	120	K/W
	amplem		[1][5][3]	-	-	60	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[6]</u>	-	-	12	K/W

 For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Reflow soldering is the only recommended soldering method.

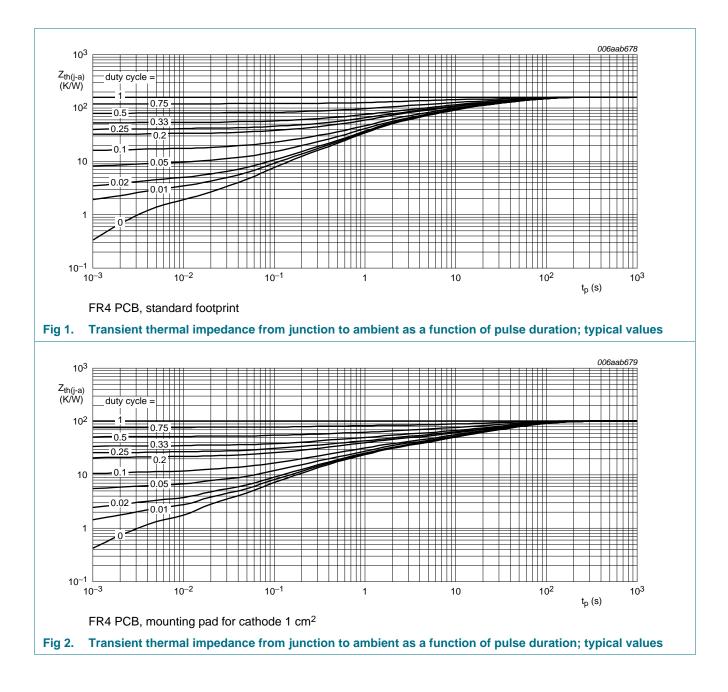
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

[6] Soldering point of cathode tab.

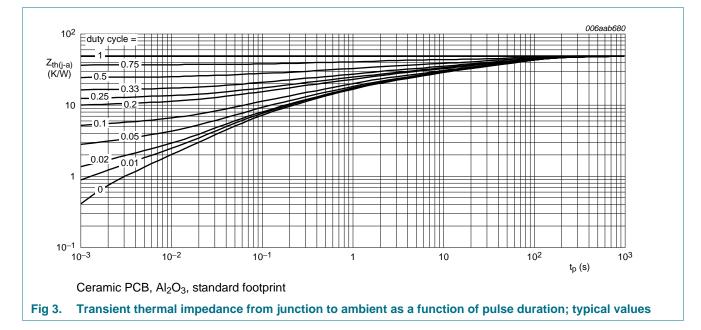
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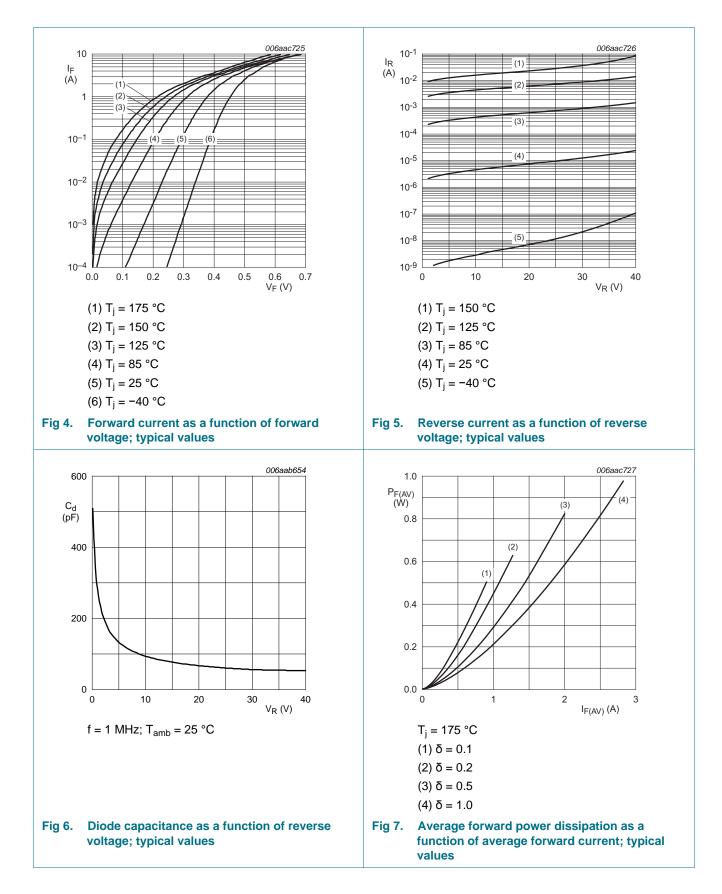
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7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 0.1 A; T _j = 25 °C	-	295	330	mV
		I _F = 1 A; T _j = 25 °C	-	380	440	mV
		I _F = 2 A; T _j = 25 °C	-	430	490	mV
		I _F = 2 A; T _j = 125 °C	-	330	380	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C	-	5	-	μΑ
		V _R = 40 V; T _j = 25 °C	-	25	100	μΑ
		V _R = 10 V; T _j = 125 °C	-	4	-	mA
		V _R = 40 V; T _j = 125 °C	-	15	-	mA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	250	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	95	-	pF

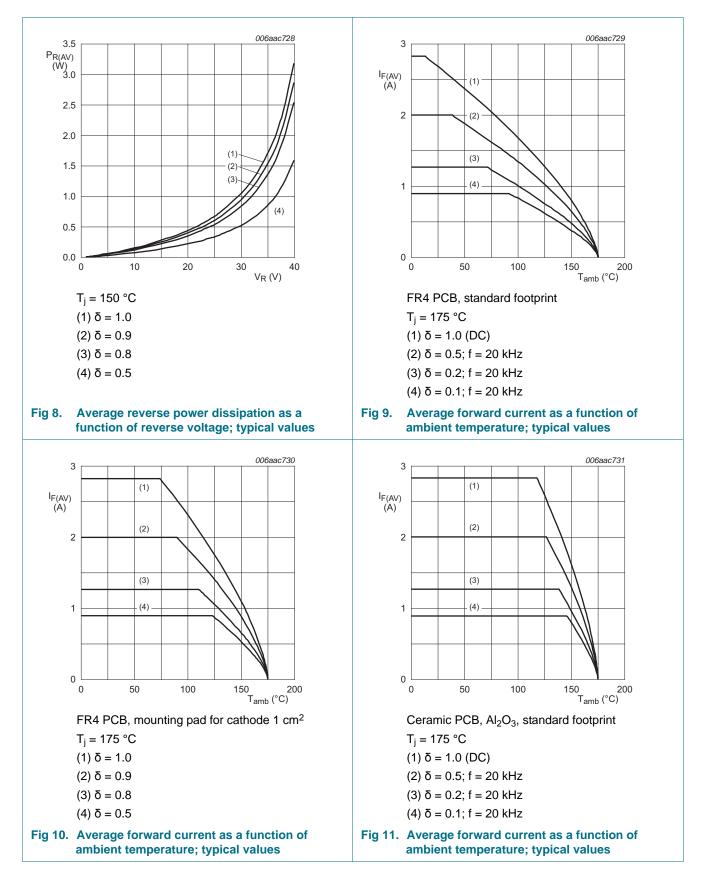
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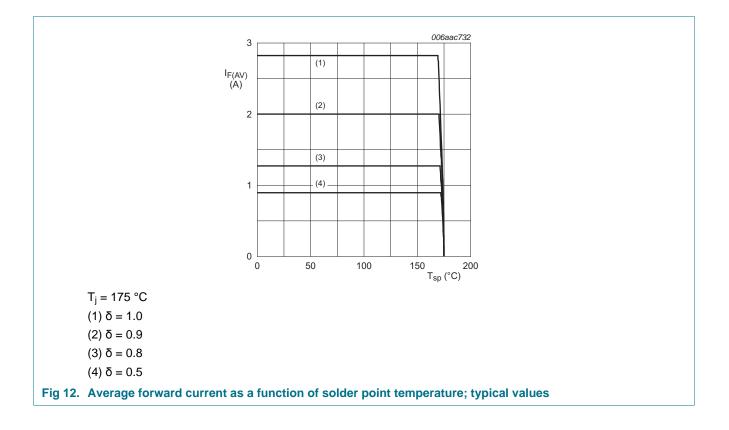


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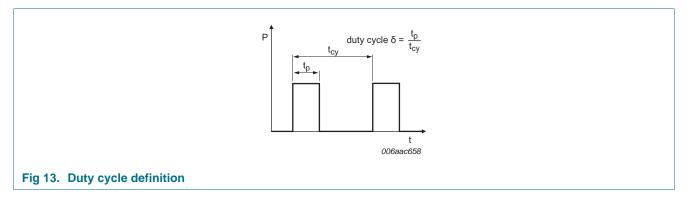
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8. Test information

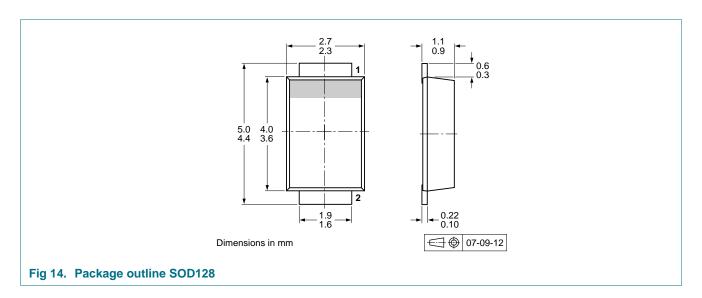


The current ratings for the typical waveforms as shown in figures 9, 10, 11 and 12 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline



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10. Packing information

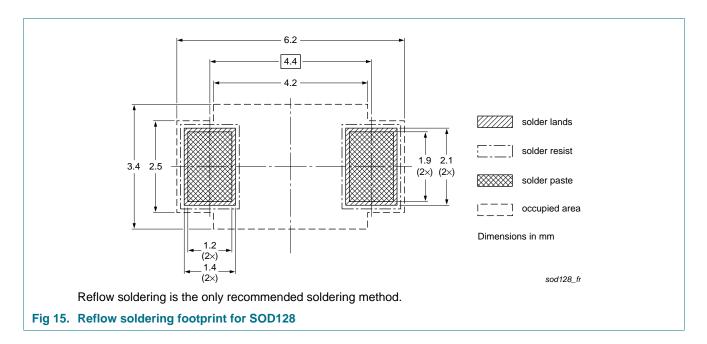
Table 8. Ordering information

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity
			3000
PMEG4020ETP	SOD128	4 mm pitch, 12 mm tape and reel	-115

[1] For further information and the availability of packing methods, see 14 "Contact information".

11. Soldering



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12. Revision history

Table 9. Revision h	9. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PMEG4020ETP v.1	20111005	Product data sheet	-	-	

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13. Legal information

13.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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